



Patent
Docket: 90065.001020 (XDEV1100)
Reply to Office Action of 12 May 2004

2815
\$
CC

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

Applicant	:	Martin E. Kordesch, et al.)	
Serial No.	:	09/682,151)	
Filed	:	27 July 2001)	Examiner: Baumeister
For	:	CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND SEMICONDUCTOR DEVICES FORMED BY THOSE METHODS)	Art Unit: 2815

AMENDMENT

Commissioner for Patents
MS: AMENDMENT
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action mailed 12 May 2004 and having a shortened statutory period for response set to expire on 12 August 2004, which period has been extended to expire on 12 September 2004 by the enclosed Petition for Extension of Time, Applicants hereby submit the following Amendment and Response.

CERTIFICATE OF MAILING BY FIRST CLASS MAIL (37 CFR 1.8)Applicant(s): **Keith D. Jamison and Michael L. Kempel**

Docket No.

90065.001020(XDEV1100)

Application No.

09/682,151

Filing Date

July 27, 2001

Examiner

Bradley W. Baumeister

Customer No.

34799

Group Art Unit

2815

Invention: **CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND SEMICONDUCTOR
DEVICES FORMED BY THOSE METHODS**

I hereby certify that this Amendment (16 pages)

(Identify type of correspondence)

is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope
addressed to "Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450" [37 CFR 1.8(a)] on
September 9, 2004

(Date)

Kathleen A. Manczuk

(Typed or Printed Name of Person Mailing Correspondence)

Kathleen A. Manczuk

(Signature of Person Mailing Correspondence)

Note: Each paper must have its own certificate of mailing.